

Vishay Semiconductors

Schottky Rectifier, 1.0 A



- Ultralow forward voltage drop
- Optimized for OR-ing applications
- Guard ring for enhanced ruggedness and long term reliability
- 125 °C T_J operation (V_R < 5 V)
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

The VS-10BQ015PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.0	А		
V _{RRM}		15	V		
I _{FSM}	t _p = 5 μs sine	140	А		
V _F	1.0 Apk, T _J = 125 °C	0.32	V		
TJ	Range	- 55 to 125	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10BQ015PbF	UNITS	
Maximum DC reverse voltage	V _R	15	M	
Maximum working peak reverse voltage	V _{RWM}	25	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_L = 84 °C, rectangular waveform		1.0	А
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	140	A
See fig. 7		10 ms sine or 6 ms rect. pulse	V_{RRM} applied	40	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 2 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А

Document Number: 94110 Revision: 15-Nov-10 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com



COMPLIANT





Cathode Anode

PRODUCT SUMMARY				
Package	SMB (DO-214AA)			
I _{F(AV)}	1 A			
V _R	15 V			
V _F at I _F	0.32 V			
I _{RM}	12 mA at 100 °C			
T _J max.	125 °C			
Diode variation	Single die			
E _{AS}	1 mJ			

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST C	VALUES	UNITS	
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	1 A	T _{.1} = 25 °C	0.35	V
		2 A	- 1j = 25 C	0.44	
		1 A	T _{.1} = 125 °C	0.32	
		2 A	1j = 125 C	0.40	
Maximum reverse leakage current See fig. 2	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.5	mA
		T _J = 100 °C		12	
Threshold voltage	V _{F(TO)}	- T _J = T _J maximum		-	V
Forward slope resistance	r _t			-	mΩ
Typical junction capacitance	CT	V_{R} = 5 V_{DC} , (test signal range 100 kHz to 1 MHz), 25 °C		390	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		- 55 to 125	°C
Maximum storage temperature range	T _{Stg}		- 55 to 150	U
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	36	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	C/W
Approvingets weight			0.10	g
Approximate weight			0.003	oz.
Marking device		Case style SMB (similar to DO-214AA)	V1C	

Notes

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB



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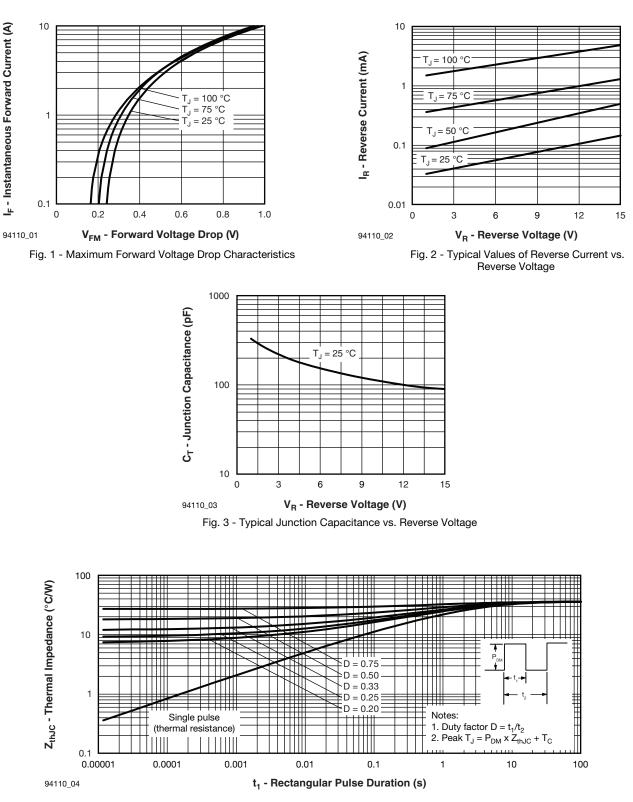


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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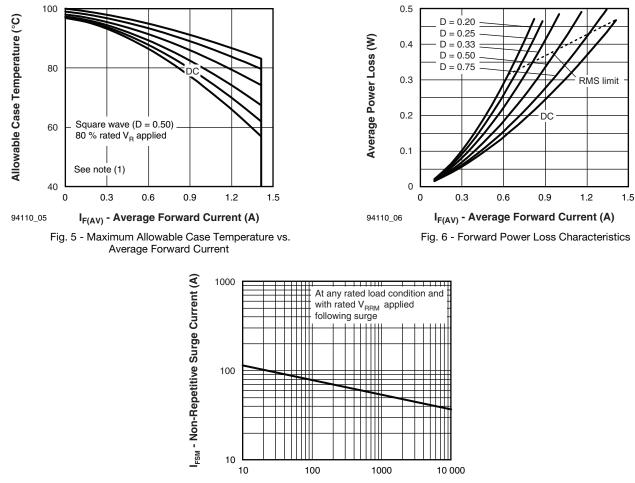
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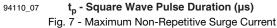
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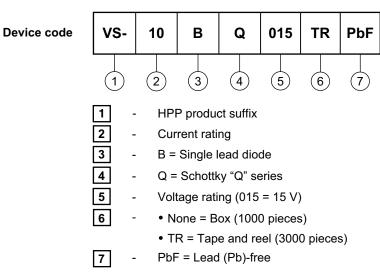
Note

- (1)
- $\begin{array}{l} \mbox{Formula used: } T_C = T_J \mbox{ } (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \mbox{Forward power loss} = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = \ Inverse \ power \ loss = V_{R1} \ x \ I_R \ (1 \ D); \ I_R \ at \ V_{R1} = 80 \ \% \ rated \ V_R \end{array}$



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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95017			
Part marking information		www.vishay.com/doc?95029		
Deckezing information	Tape and reel	www.vishay.com/doc?95034		
Packaging information	Bulk	www.vishay.com/doc?95397		
SPICE model		www.vishay.com/doc?95355		

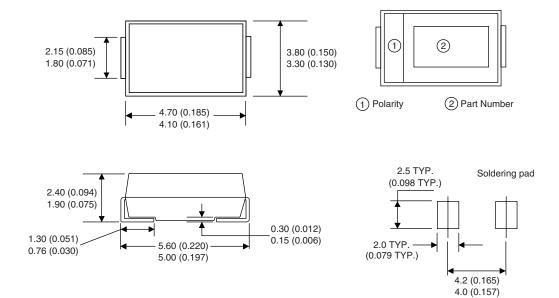


Outline Dimensions

Vishay High Power Products

SMB

DIMENSIONS in millimeters (inches)





Vishay

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